

Precision, 8-Channel/Dual 4-Channel, High-Performance, CMOS Analog Multiplexers

General Description

The MAX308/MAX309 precision, monolithic, CMOS analog multiplexers (muxes) offer low on-resistance (less than 100Ω), which is matched to within 5Ω between channels and remains flat over the specified analog signal range (7 Ω max). They also offer low leakage over temperature (NO-off leakage current less than 5nA at +85°C) and fast switching speeds (transition time less than 250ns). The MAX308 is a single-ended 1-of-8 device, and the MAX309 is a differential 2-of-4 device.

The MAX308/MAX309 are fabricated with Maxim's improved 44V silicon-gate process. Design improvements yield extremely low charge injection (less than 10pC) and guarantee electrostatic discharge protection greater than 2000V.

These muxes operate with a single +5V to +30V supply or bipolar ±5V to ±20V supplies, while retaining TTL/CMOS-logic input compatibility and fast switching. CMOS inputs provide reduced input loading. These improved parts are plug-in upgrades for the industrystandard DG408, DG409, DG508A, and DG509A.

Applications

Sample-and-Hold Circuits

Automatic Test Equipment

Heads-Up Displays

Guidance and Control Systems

Military Radios

Communications Systems

Battery-Operated Systems

PBX, PABX

Audio Signal Routing

Features

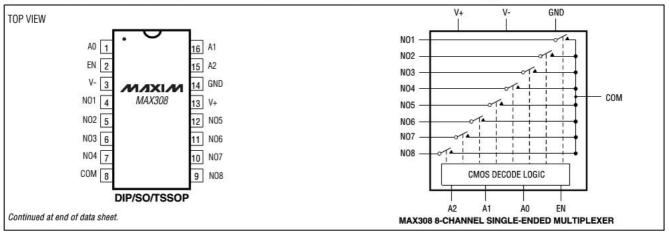
- **Guaranteed On-Resistance Match Between** Channels, $<5\Omega$ Max
- ♦ Low On-Resistance, <100Ω Max</p>
- Guaranteed Flat On-Resistance over Specified Signal Range, 7Ω Max
- Guarateed Low Charge Injection, <10pC
- NO-Off Leakage Current <5nA at +85°C
- COM-Off Leakage Current <20nA at +85°C
- ESD Protection >2000V
- Plug-In Upgrade for Industry-Standard DG408/DG409/DG508A/DG509A
- Single-Supply Operation (+5V to +30V) Bipolar-Supply Operation (±5V to ±20V)
- Low Power Consumption, <300µW
- Rail-to-Rail Signal Handling
- TTL/CMOS-Logic Compatible

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX308CPE	0°C to +70°C	16 Plastic DIP
MAX308CSE	0°C to +70°C	16 Narrow SO
MAX308C/D	0°C to +70°C	Dice*
MAX308CUE	0°C to +70°C	16 TSSOP
MAX308EPE	-40°C to +85°C	16 Plastic DIP
MAX308ESE	-40°C to +85°C	16 Narrow SO
MAX308EJE	-40°C to +85°C	16 CERDIP
MAX308EUE	-40°C to +85°C	16 TSSOP
MAX308MJE	-55°C to +125°C	16 CERDIP**
	1049 State 96 St	5155 W. U.Sek 99 Sek

Ordering Information continued at end of data sheet.

Pin Configurations/Functional Diagrams/Truth Tables



MIXIM

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For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

^{*}Contact factory for dice specifications. **Contact factory for availability.

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to V-	
V+	0.3V, 44V
GND	
Digital Inputs, NO, COM (Note 1)	(V 2V) to (V+ + 2V) or
30m.	A, (whichever occurs first)
Continuous Current (any terminal)	30mA
Peak Current, NO or COM	
(pulsed at 1ms, 10% duty cycle ma	x)100mA

Continuous Power Dissipation (TA = +70°C	()
Plastic DIP (derate 10.53mW/°C above +	70°C)842mW
Narrow SO (derate 8.70mW/°C above +7	70°C)696mW
CERDIP (derate 10.00mW/°C above +70	0°C)800mW
TSSOP (derate 6.7mW/°C above +70°C)	457mW
Operating Temperature Ranges	
MAX30_C	0°C to +70°C
MAX30_E	40°C to +85°C
MAX30_MJE	55°C to +125°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10sec)	

Note 1: Signals on NO, COM, EN, A0, A1, or A2 exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = +15V, V- = -15V, GND = 0V, VAH = +2.4V, VAL = +0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS				MIN	TYP (Note 2)	MAX	UNITS	
SWITCH										
Analog Signal Range	V _{NO} , V _{COM}	(Note 3)				-15		15	V	
On-Resistance	Ron	$I_{NO} = -1.0 mA$,		T _A = +25°C			60	100	Ω	
On-nesistance	HON	$V_{COM} = \pm 10V$		T _A = T _{MIN} t	о Тмах			125	32	
On-Resistance Matching	ΔRon	I _{NO} = -1.0mA,		T _A = +25°C			1.5	5	Ω	
Between Channels	ANON	Vcом = ±10V (101/01/01		о Тмах			8	32	
On-Resistance Flatness	Deute	I _{NO} = -1.0mA,		T _A = +25°C			1.8	7	Ω	
On-nesistance riatiless	Ress Relat $V_{COM} = \pm 5V \text{ or } 0V$	r OV	T _A = T _{MIN} t	о Тмах			10] 32		
NO 0"1 1 0		V _{COM} = +10V,		T _A = +25°C		-0.5	0.01	0.5		
NO-Off Leakage Current (Note 5)	INO(OFF)	V _{NO} = ±10V, V _{EN} = 0V		T _A = T _{MIN}	C, E	-2.5		2.5	nA	
				to T _{MAX}	М	-5.0		5.0		
		VNO = ±10V,		T _A = +25°C		-0.75	0.02	0.75	5	
COM-Off Leakage Current (Note 5)	62	V _{COM} = +10V, V _{EN} = 0V	MAX308	T _A = T _{MIN}	C, E	-10		10		
				to T _{MAX}	М	-20		20	- ^	
	ICOM(OFF)	V _{NO} = +10V, V _{COM} = ±10V, M		T _A = +25°C		-0.75	0.02	0.75	nA	
			MAX309	T _A = T _{MIN}	C, E	-5		5	1	
		VEN = 0V		to T _{MAX}	М	-10		10		
				T _A = +25°C		-0.75	0.02	0.75		
COM-On Leakage Current	1000000	$V_{NO} = \pm 10V$,	MAX308	T _A = T _{MIN}	C, E	-10		10	1	
				to T _{MAX}	М	-20		20	nA	
(Note 5)	ICOM(ON)	sequence each switch		T _A = +25°C		-0.75	0.02	0.75	1 IIA	
		on	MAX309	T _A = T _{MIN}	C, E	-5		5	1	
		1.5	(30.000)	to T _{MAX}	М	-10		10	1	

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V+ = +15V, V- = -15V, GND = 0V, VAH = +2.4V, VAL = +0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDIT		TIONS	MIN	TYP (Note 2)	MAX	UNITS	
INPUT								1	
Input Current with Input Voltage High	I _{AH}	V _A = 2.4V or 15	V		-1.0		1.0	μА	
Input Current with Input Voltage Low	I _{AL}	V _{EN} = 0V or 2.4' V _A = 0V	V,		-1.0		1.0	μА	
SUPPLY									
Power-Supply Range			1-0		±5		±20	V	
- 1000		VEN = VA = 0V o	or 4 EV	T _A = +25°C		16	30		
Positive Supply Current	I+	VEN = VA = UV C	JI 4.5V	$T_A = T_{MIN}$ to T_{MAX}			75	μA mA	
rositive Supply Current	1+	V _{EN} = 2.4V,		T _A = +25°C		0.075	0.5		
		$V_{A(ALL)} = 0V$ or	2.4V	$T_A = T_{MIN}$ to T_{MAX}					
Negative Supply Current	1-	$V_{EN} = 2.4V$,	68	$T_A = +25^{\circ}C$	-1		1	μA	
	317	V _{A(ALL)} = 0V or 2.4V		$T_A = T_{MIN}$ to T_{MAX}	-10		10	μД	
DYNAMIC					-	.1000			
Transistion Time	ttrans	Figure 2	325	$T_A = +25^{\circ}C$		85	175	50 ns	
	THANS	1970		$T_A = T_{MIN}$ to T_{MAX}		855	250		
Break-Before-Make Interval	topen	Figure 4		T _A = +25°C	10	40		ns	
Enable Turn-On Time	ton(EN)	Figure 3		$T_A = +25^{\circ}C$		85	150	ns	
	0.0000000000000000000000000000000000000			$T_A = T_{MIN}$ to T_{MAX}			225		
Enable Turn-Off Time	toff(EN)	Figure 3		$T_A = +25^{\circ}C$			150	ns	
Charge Injection		$C_L = 1.0nF,$		$T_A = T_{MIN}$ to T_{MAX}			300		
(Note 3)	Q	$V_{NO} = 0V$, $R_S = 0\Omega$, Figure	5	T _A = +25°C		2	10	рС	
Off Isolation (Note 6)	V _{ISO}	$V_{EN} = 0V$, $R_L = 1k\Omega$, f = 100kHz, Figu	ure 6	T _A = +25°C		-75		dB	
Crosstalk Between Channels	Vст	$\begin{split} V_{EN} &= 2.4 \text{V}, \\ f &= 100 \text{kHz}, \\ V_{GEN} &= 1 \text{V}_{P\text{-P}}, \\ R_L &= 1 \text{k} \Omega, \text{ Figure} \end{split}$	e 7	T _A = +25°C		-92		dB	
Logic Input Capacitance	CIN	f = 1MHz	(2)	T _A = +25°C		8		pF	
NO-Off Capacitance	C _{NO(OFF)}	f = 1MHz, VEN = VNO = 0V Figure 8	/,	T _A = +25°C		3		pF	
COM-Off Capacitance	Ссом(оff)	f = 1MHz, V _{EN} = 0.8V V _{COM} = 0V,	MAX308	T _A = +25°C		26		pF	
	20 53	Figure 8	MAX309			14			
COM-On Capacitance	CCOM(ON)	f = 1MHz, V _{EN} = 2.4V	MAX308	T _A = +25°C		37		pF	
	200(0.1)	V _{COM} = 0V, Figure 8	MAX309	500		25			

ELECTRICAL CHARACTERISTICS—Single Supply

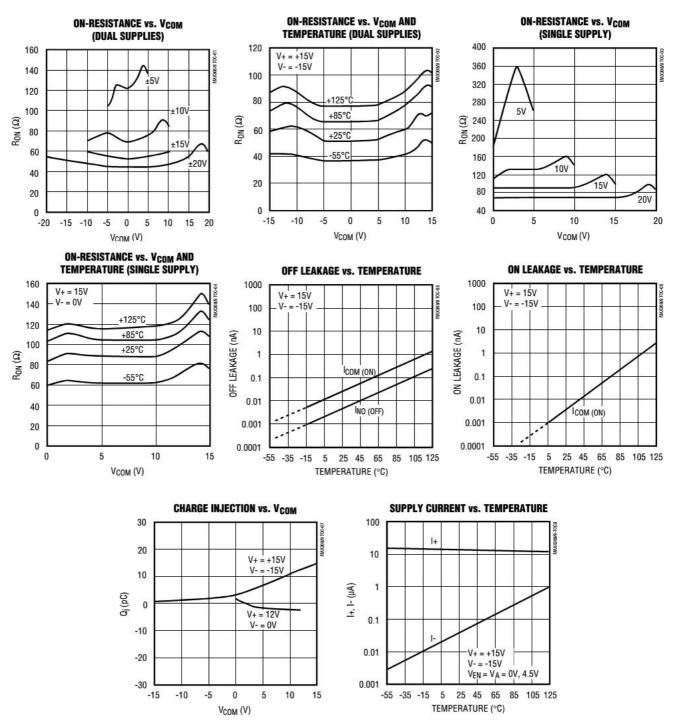
(V+ = +12V, V- = 0V, GND = 0V, VAH = +2.4V, VAL = +0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	coi	NDITIONS	MIN	TYP (Note 2)	MAX	UNITS
SWITCH	'			'			
Analog Signal Range	V _{NO} , V _{COM}	(Note 3)		0		12	V
On-Resistance	R _{ON}	I _{NO} = -1.0mA V _{COM} = 3V or 10V	T _A = +25°C		120	175	Ω
DYNAMIC							
Transition Time (Note 3)	t _{TRANS}	V _{NO1} = 8V, V _{NO8} = 0V, V _{IN} = 2.4V, Figure 2	T _A = +25°C		115	450	ns
Enable Turn-On Time (Note 3)	tON(EN)	V _{INH} = 2.4V, V _{INL} = 0V, V _{NO1} = 5V, Figure 3	T _A = +25°C		100	600	ns
Enable Turn-Off Time (Note 3)	tOFF(EN)	V _{INH} = 2.4V, V _{INL} = 0V, V _{NO1} = 5V, Figure 3	T _A = +25°C		75	300	ns
Charge Injection (Note 3)	Q	$C_L = 1.0 nF,$ $V_{NO} = 0V,$ $R_S = 0\Omega$	T _A = +25°C		2	10	pC

- Note 2: The algebraic convention where the most negative value is a minimum and the most positive value a maximum is used in this data sheet.
- Note 3: Guaranteed by design.
- Note 4: ΔR_{ON} = R_{ON(MAX)} R_{ON(MIN)}. On-resistance match between channels and flatness are guaranteed only with specified voltages. Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured at the extremes of the specified analog signal range.
- Note 5: Leakage parameters are 100% tested at the maximum rated hot temperature and guaranteed by correlation at +25°C.
- Note 6: Off isolation = 20log VCOM/VNO, where VCOM = output and VNO = input to off switch.

Typical Operating Characteristics

 $(T_A = +25^{\circ}C, unless otherwise noted.)$



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Pin Description

P	IN	NAME	FUNCTION
MAX308	MAX309	NAME	FUNCTION
1, 15, 16	2_2	A0, A2, A1	Address Inputs
V2	1, 16	A0, A1	Address Inputs
2	2	EN	Enable Input
3	3	V-	Negative Supply Voltage Input
4–7	<u></u>	NO1-NO4	Analog Inputs—Bidirectional
81	4–7	NO1A-NO4A	Analog Inputs—Bidirectional
8	_	COM	Analog Output—Bidirectional
S	8, 9	COMA, COMB	Analog Outputs—Bidirectional
9–12	=	NO8-NO5	Analog Inputs—Bidirectional
85 <u></u>	10–13	NO4B-NO1B	Analog Inputs—Bidirectional
13	14	V+	Positive Supply Voltage Input
14	15	GND	Ground

Applications Information

Operation with Supply Voltages Other than 15V

Using supply voltages less than ±15V will reduce the analog signal range. The MAX308/MAX309 switches operate with ±5V to ±20V bipolar supplies or with a +5V to +30V single supply. Connect V- to GND when operating with a single supply. Both device types can also operate with unbalanced supplies, such as +24V and -5V. The *Typical Operating Characteristics* graphs show typical on-resistance with 20V, 15V, 10V, and 5V supplies. (Switching times increase by a factor of two or more for operation at 5V.)

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs, NO, or COM. If power-supply sequencing is not possible, add two small signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to 1V below V+ and 1V above V-, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed +44V.

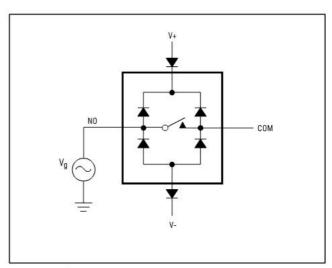


Figure 1. Overvoltage Protection Using External Blocking Diodes

Test Circuits/Timing Diagrams

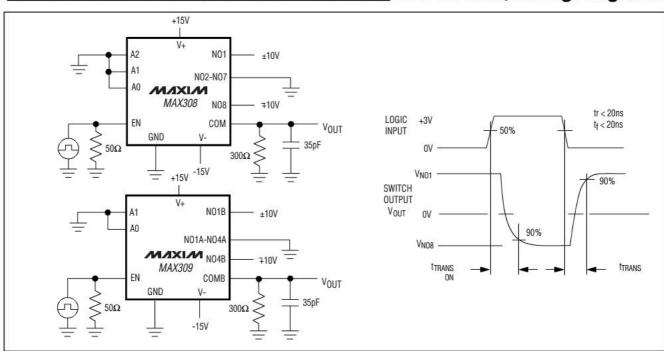


Figure 2. Transition Time

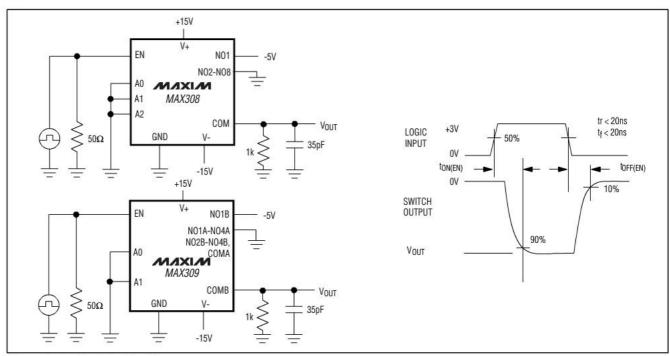


Figure 3. Enable Switching Time

Test Circuits/Timing Diagrams (continued)

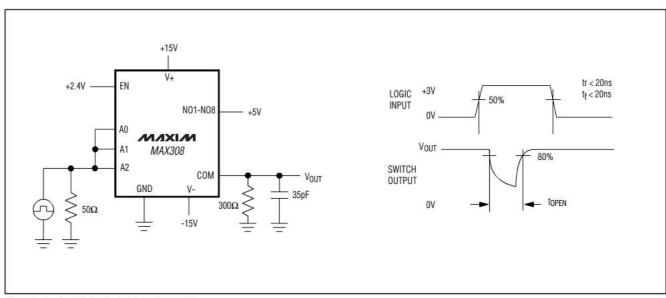


Figure 4. Break-Before-Make Interval

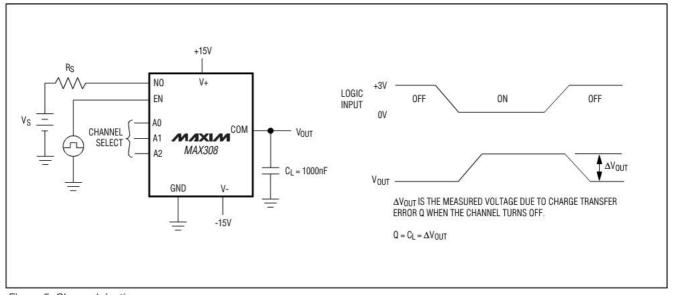


Figure 5. Charge Injection

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Test Circuits/Timing Diagrams (continued)

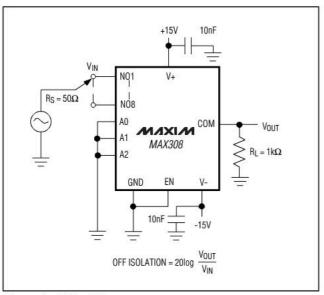


Figure 6. Off Isolation

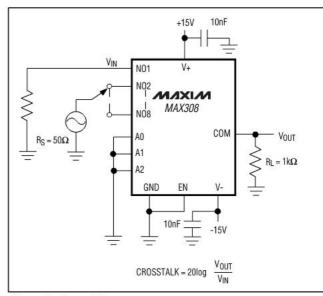


Figure 7. Crosstalk

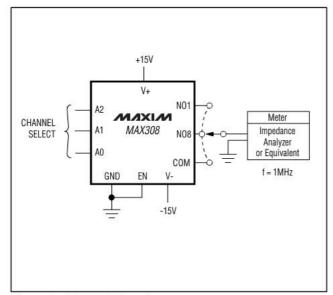
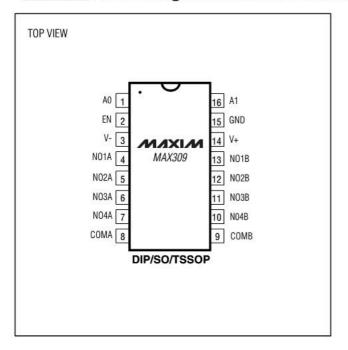
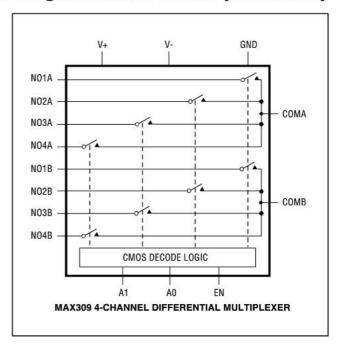


Figure 8. NO/COM Capacitance

Pin Configurations/Functional Diagrams/Truth Tables (continued)





X	A2	A 1	A0	EN	ON SWITCH
0 0 1 1 2 0 1 0 1 3 0 1 1 1 4 1 0 0 1 5 1 0 1 1 6 1 1 0 1 7 1 1 1 1 8	Χ	Х	Х	0	None
0 1 0 1 3 0 1 1 1 4 1 0 0 1 5 1 0 1 1 6 1 1 0 1 7 1 1 1 1 8	0	0	0	1	1
0 1 1 1 4 1 0 0 1 5 1 0 1 1 6 1 1 0 1 7 1 1 1 1 8	0	0	1	1	2
1 0 0 1 5 1 0 1 1 6 1 1 0 1 7 1 1 1 1 8	0	1	0	1	3
1 0 1 1 6 1 1 0 1 7 1 1 1 1 8	0	1	1	1	4
1 1 0 1 7 1 1 1 8	1	0	0	1	5
1 1 1 8	1	0	1	1	6
	1	1	0	1	7
MAY208	1	1	1	1	8
WAASUU			MAX	308	

A1	A0	EN	ON SWITCH
Х	Х	0	None
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4
	М	AX309	

Ordering Information (continued)

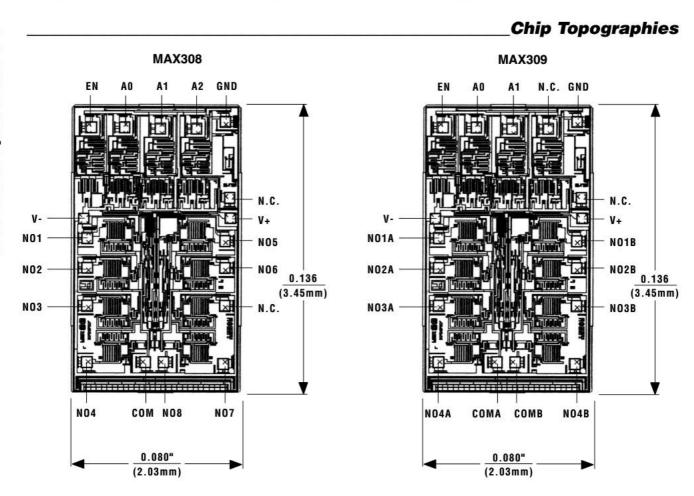
PART	TEMP RANGE	PIN-PACKAGE
MAX309CPE	0°C to +70°C	16 Plastic DIP
MAX309CSE	0°C to +70°C	16 Narrow SO
MAX309CUE	0°C to +70°C	16 TSSOP
MAX309C/D	0°C to +70°C	Dice*
MAX309EPE	-40°C to +85°C	16 Plastic DIP
MAX309ESE	-40°C to +85°C	16 Narrow SO
MAX309EJE	-40°C to +85°C	16 CERDIP
MAX309EUE	-40°C to +85°C	16 TSSOP
MAX309M.IF	-55°C to +125°C	16 CERDIP**

^{*}Contact factory for dice specifications.

_Package Information

For the latest package outline information, go to **www.maxim-ic.com/packages**.

^{**} Contact factory for availability.



N.C. = NO INTERNAL CONNECTION

TRANSISTOR COUNT: 122 SUBSTRATE CONNECTED TO V+ TRANSISTOR COUNT: 122 SUBSTRATE CONNECTED TO V+

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